Analog Power AM2398N

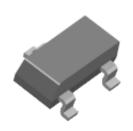
N-Channel 60V (D-S) MOSFET

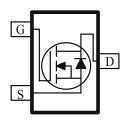
These miniature surface mount MOSFETs utilize High Cell Density process. Low $r_{DS(on)}$ assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are power switch, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low $r_{DS(on)}$ Provides Higher Efficiency and
	Extends Battery Life

- Low Gate Charge
- Fast Switch
- Miniature SOT-23 Surface Mount Package Saves Board Space

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)}(\Omega)$ $I_{D}(A)$			
60	$0.194 @ V_{GS} = 10 V$	2.2		
00	$0.273 @ V_{GS} = 4.5V$	1.8		





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Maximum	Units	
Drain-Source Voltage		V_{DS}	60	V	
Gate-Source Voltage		V_{GS}	±20	V	
C (P · C · (a	$T_A=25^{\circ}C$		2.2		
Continuous Drain Current ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	1D	1.7	A	
Pulsed Drain Current ^b		I_{DM}	±15		
Continuous Source Current (Diode Conduction) ^a		I_S	1.7	A	
D D: : ,: a	$T_A=25^{\circ}C$	D	1.3	W	
Power Dissipation ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	PD	0.8	•••	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
N. T. (* A. 1 · (a	t <= 5 sec	D	100	0C/M		
Maximum Junction-to-Ambient ^a	Steady-State	R_{THJA}	166	T C/W		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Davierentes	6	T C. 122	Limits			TT •4	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1.0			V	
Gate-Body Leakage	Igss	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$			1	uА	
-	1088	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			50	uA	
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			A	
Drain-Source On-Resistance ^A		$V_{GS} = 10 \text{ V}, I_D = 2.2 \text{ A}$			194	mΩ	
Drain-Source On-Resistance	fDS(on)	$V_{GS} = 4.5 \text{ V}, I_D = 1.8 \text{ A}$			273		
Forward Tranconductance ^A	gs	$V_{DS} = 4.5 \text{ V}, I_D = 2.2 \text{ A}$		8		S	
Diode Forward Voltage	V_{SD}	$I_S = 1.7 A, V_{GS} = 0 V$			1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			4.0			
Gate-Source Charge Qgs V		$V_{DS} = 30 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 2.2 \text{ A}$		4.0		nC	
Gate-Drain Charge	Qgd			2.0			
Turn-On Delay Time	t _{d(on)}			10			
Rise Time	$t_{\rm r}$	$V_{DD} = 30 \text{ V}, R_L = 30 \Omega, I_D = 1 \text{ A},$		10			
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = 10 \text{ V}$		20		ns	
Fall-Time	t_{f}			10			
Source-Ddrain Reverse Recovery Time	t _{rr}	$I_F = 1.7 \text{ A}, di/dt = 100 \text{ A/uS}$		50			

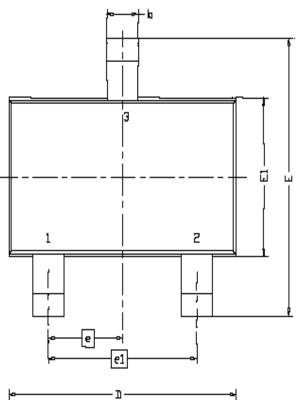
Notes

a. Pulse test: $PW \le 300us duty cycle \le 2\%$.

b. Guaranteed by design, not subject to production testing.

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Package Information



DIM.	MIL	LIMETE	RS	
ייונת	MIN	NDM	MAX	
Α	0.935	0.95	1.10	
A1	0.01	-	0.10	
A2	0.85	0.90	1.925	
Ь	0.30	0.40	0.50	
С	0.10	0.15	0,25	
D	2.70	2.90	3.10	
П	2.60	2.80	3.00	
E1	1.40	1.60	1.80	
6	0.95 BSC			
el	1.90 BSC			
L	0.30	0.40	0.60	
L1	0.60REF			
LZ	0,25BSC			
R	0.10			
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01	7*N□M			

